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Spestitute for form 1449A/B/PTO

## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Sheet 1 of

	Complete if Known				
Application Number	10/612,974				
Filing Date	July 7, 2003				
First Named Inventor	Chandra Mouli				
Art Unit	N/A				
Examiner Name Not Yet Assigned					
Attorney Docket Number	M4065.0941/P941				

			U.S. PA	TENT DOCUMENTS	
Examiner Initials*	Cite No.1	Document Number  Number-Kind Code <sup>2</sup> ( if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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FOREIGN PATENT DOCUMENTS							
Examiner Initials*	Cite No.1	Foreign Patent Document  Country Code <sup>3</sup> -Number <sup>4</sup> -Kind Code <sup>5</sup> (# known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		

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	NON PATENT LITERATURE DOCUMENTS					
Examiner Initials	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>			
M	CA	ILIANA L. FUJIMORI et al., "A 256x256 CMOS DIFFERENTIAL PASSIVE PIXEL IMAGER WITH FPN REDUCTION TECHNIQUES," IEEE Journal of Solid-Stat eCircuits, Vol. 35, No.12, December 2000.				
1	СВ	PETER SINGER, "Strained Silicon Ready for Prime Time," Semiconductor International, 11/1/2002.				

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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Substitu	ite for form 1449A/B/	PTO		Complete if Known			
				Application Number	10/612,974-Conf. #4728	_	
INF	ORMATIC	N DI	SCLOSURE	Filing Date	July 7, 2003		
STA	ATEMENT	BY	APPLICANT	First Named Inventor	Chandra Mouli		
				Art Unit	2871	_	
	(Use as many	sheets as	necessary)	Examiner Name	Not Yet Assigned		
heet	1	of	1	Attorney Docket Number	M4065 0941/P941		

	U.S. PATENT DOCUMENTS							
Examiner	Cite	Document Number	Publication Date	Traine or Catenas or	Pages, Columns, Lines, Where Relevant Passages or Relevant			
Initials*	No.1	Number-Kind Code* ( if known)	MIM-DD-TTTT	Applicant of Cited Document	Figures Appear			
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	FOREIGN PATENT DOCUMENTS								
Examin Initials*		Cite No.1	Foreign Patent Document  Country Code <sup>3</sup> -Number <sup>4</sup> -Kind Code <sup>5</sup> (If known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear			
		BA	EP 0 940 854 A2	09-08-99					
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	CA	FREEMAN, G. JAGANNATHAN, B., ZAMDMER, R., GROVES, SINGH, Y., TRETIAKOV, KUMAR, M., JOHNSON, J., PLOUCHART, J., GREENBERT, D., KOESTER, S., SCHAUB, J. Integrated SiGe and Si Device Capabilities and Trends for Multi-Gigahertz Applications, Internatioal Journal of High Speed Electronics and Systems, Vol. 13, No. 1 (2003) pgs. 175-219	
لر	СВ	MAITI, C., BERA, L. AND CHATTOPADHYAY, S. Topical Review Strained-Si Heterostructure Field Effect Transistors, Semiconductor Science Technology 13 (1998) pgs. 1225-1246.	

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Examiner Signature	Keth 11	oul	Date Considered	3/10/06
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